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APPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO	
10/024,208	12/21/2001	David J. Cooperberg	015290-546	9076	
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Peter K. Skiff			ALEJANDRO MULERO, LUZ L		
BURNS, DOANE, SWECKER & MATHIS, L.L.P. P.O. Box 1404			ART UNIT	PAPER NUMBER	
Alexandria, VA 22313-1404			1763		

DATE MAILED: 03/15/2004

Please find below and/or attached an Office communication concerning this application or proceeding.

	Application	No.	Applicant(s)				
0.00	10/024,208		COOPERBERG ET AL.				
Office Action Summary	Examiner		Art Unit				
	Luz L. Aleja		1763				
The MAILING DATE of this comm Period for Reply	unication appears on the o	cover sheet with the co	rrespondence a	ddress			
A SHORTENED STATUTORY PERIOD THE MAILING DATE OF THIS COMMU - Extensions of time may be available under the provisi after SIX (6) MONTHS from the mailing date of this co - If the period for reply specified above, the maximum - Failure to reply within the set or extended period for re Any reply received by the Office later than three month earned patent term adjustment. See 37 CFR 1.704(b)	INICATION. ons of 37 CFR 1.136(a). In no event mmunication. y (30) days, a reply within the statuto n statutory period will apply and will a ply will, by statute, cause the applic as after the mailing date of this come	, however, may a reply be time ry minimum of thirty (30) days expire SIX (6) MONTHS from the ation to become ABANDONED	ely filed will be considered time he mailing date of this o				
Status							
1) Responsive to communication(s)	filed on <u>19 December 200</u>	<u>)3</u> .					
2a)☐ This action is FINAL .	This action is FINAL . 2b)⊠ This action is non-final.						
3) Since this application is in condition closed in accordance with the practice.				e merits is			
Disposition of Claims							
4) ⊠ Claim(s) <u>1-15 and 39-42</u> is/are pe 4a) Of the above claim(s) is 5) □ Claim(s) is/are allowed. 6) ⊠ Claim(s) <u>1-15 and 39-42</u> is/are rej 7) □ Claim(s) is/are objected to. 8) □ Claim(s) are subject to rest	s/are withdrawn from consected.						
Application Papers							
9) The specification is objected to by	the Examiner.						
10) The drawing(s) filed on is/a	0)☐ The drawing(s) filed on is/are: a)☐ accepted or b)☐ objected to by the Examiner.						
Applicant may not request that any ob	jection to the drawing(s) be	held in abeyance. See	37 CFR 1.85(a).				
Replacement drawing sheet(s) include	•	=		• ,			
11) The oath or declaration is objected	I to by the Examiner. Note	the attached Office A	Action or form P	TO-152.			
Priority under 35 U.S.C. § 119							
12) Acknowledgment is made of a clai a) All b) Some * c) None of: 1. Certified copies of the priori 2. Certified copies of the priori 3. Copies of the certified copies application from the Interna * See the attached detailed Office ac	ty documents have been ty documents have been es of the priority documen tional Bureau (PCT Rule	received. received in Applicatio ts have been received 17.2(a)).	n No d in this National	l Stage			
Attachment(s)							
1) ⊠ Notice of References Cited (PTO-892) 2) ☑ Notice of Draftsperson's Patent Drawing Review) Interview Summary (I Paper No(s)/Mail Date	°TO-413) e.				
2) Notice of Draitspersor's Faterit Drawing Review 3) Information Disclosure Statement(s) (PTO-1449 Paper No(s)/Mail Date	or PTO/SB/08) 5) Notice of Informal Pa) Other:		O-152)			

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DETAILED ACTION

Continued Examination Under 37 CFR 1.114

A request for continued examination under 37 CFR 1.114, including the fee set forth in 37 CFR 1.17(e), was filed in this application after final rejection. Since this application is eligible for continued examination under 37 CFR 1.114, and the fee set forth in 37 CFR 1.17(e) has been timely paid, the finality of the previous Office action has been withdrawn pursuant to 37 CFR 1.114. Applicant's submission filed on 12/19/03 has been entered.

Claim Rejections - 35 USC § 102

The following is a quotation of the appropriate paragraphs of 35 U.S.C. 102 that form the basis for the rejections under this section made in this Office action:

A person shall be entitled to a patent unless -

(b) the invention was patented or described in a printed publication in this or a foreign country or in public use or on sale in this country, more than one year prior to the date of application for patent in the United States.

Claims 41-42 are rejected under 35 U.S.C. 102(b) as being anticipated by Chang, WO 99/57747.

Chang shows the invention as claimed including a plasma processing system comprising: a plasma processing chamber 38; a vacuum pump system 40 connected to the processing chamber; a substrate support 56 on which a substrate is processed within the processing chamber; a dielectric member 50 having an interior surface facing the substrate support, wherein the dielectric member forms a wall of the processing chamber; a gas injector extending through the dielectric member such that a distal end

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of the gas injector body is exposed within the processing chamber, the gas injector body including a plurality of gas outlets 96/98; means for supplying process gas at flow rates that are independently varied between at least some of the outlets into the processing chamber; and an RF energy source 89 which inductively couples RF energy through the dielectric member and into the chamber to energize the process gas into a plasma state to process the substrate. Additionally, note that the gas injector comprises an injector body including at least first and second gas inlets, at least first and second gas passages, and at least first and second gas outlets, the first gas passage being in fluid communication with the first inlet and first outlet, and the second gas passage being in fluid communication with the second inlet and second outlet, the first and second gas passages not being in fluid communication with each other. For a complete description of the apparatus see, for example, figs. 1 and 7, and their descriptions.

Claim Rejections - 35 USC § 103

The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:

(a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negatived by the manner in which the invention was made.

This application currently names joint inventors. In considering patentability of the claims under 35 U.S.C. 103(a), the examiner presumes that the subject matter of the various claims was commonly owned at the time any inventions covered therein were made absent any evidence to the contrary. Applicant is advised of the obligation

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under 37 CFR 1.56 to point out the inventor and invention dates of each claim that was not commonly owned at the time a later invention was made in order for the examiner to consider the applicability of 35 U.S.C. 103(c) and potential 35 U.S.C. 102(e), (f) or (g) prior art under 35 U.S.C. 103(a).

Claims 1-7, 9, 11-14 and 39 are rejected under 35 U.S.C. 103(a) as being unpatentable over Chang, WO 99/57747 in view of Arami et al., U.S. Patent 5,958,140, or Goodyear et al., U.S. Patent 5,532,190, or Ballance et al., U.S. Patent 6,090,210.

Chang shows the invention substantially as claimed including a plasma processing system comprising: a plasma processing chamber 38; a vacuum pump system 40 connected to the processing chamber; a substrate support 56 on which a substrate is processed within the processing chamber; a dielectric member 50 having an interior surface facing the substrate support, wherein the dielectric member forms a wall of the processing chamber; a gas injector extending through the dielectric member. the gas injector comprising a body including an axial end surface exposed within the processing chamber, a side surface extending axially from the axial end surface, and a plurality of gas outlets 96/98 including at least one on-axis outlet 96 in the axial end surface and a plurality of spaced-apart off-axis outlets 98 in the side surface; a first gas line and a second gas line, the first gas line being in fluid communication with the onaxis outlet but not with the off-axis outlets and the second gas line being in fluid communication with the off-axis outlets but not with the on-axis outlet; flow controllers operable to supply the process gases at flow rates that are independently varied between the on-axis outlet and the off-axis outlets into the processing chamber; a

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network of valves and throttling elements to vary the gas flow independently between the on-axis outlet and the off-axis outlets; and an RF energy source 89 which inductively couples RF energy through the dielectric member and into the chamber to energize the process gas into a plasma state to process the substrate. For a complete description of the apparatus see, for example, figs. 1 and 7, and their descriptions.

Chang does not expressly disclose a common gas supply in fluid communication with the first gas line and the second gas line. Arami et al., Goodyear et al., and Ballance et al., disclose an apparatus comprising a gas injecting system in which a common gas supply 41,42,43/55,56 / 314 is in fluid communication with a first gas line 38/21/312 and a second gas line 39/22/310, the first gas line being in fluid communication with a first outlet and the second line being connected to second outlets. wherein the first line is in fluid communication with the first outlet but not with the second outlets and the second gas line being in fluid communication with the second outlets but not with the first outlet (see, for example, fig. 2 of Arami et al. and its description, fig. 1 of Goodyear et al. and its description, and fig. 8 of Ballance et al. and its description). Therefore, in view of these disclosures, it would have been obvious to one of ordinary skill in the art at the time the invention was made to modify the gas supply system of the apparatus of Chang so as to comprise a common gas supply in fluid communication with the first gas line and the second gas line, in order to enable the injection of the same gas, to the processing chamber, through the on-axis outlet and the off-axis outlets. Furthermore, note that all the references disclose the use of flow controllers operable to supply the process gas from the common gas supply at flow rates that are

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independently varied toward the first line and the second line. Also, Arami et al. and Goodyear et al. disclose the use of a network of gas valves and throttling elements to independently vary the gas flow.

Additionally, note that the system of Chang is a high density plasma chemical vapor deposition system (see page 6-line 22); the RF energy source comprises an RF antenna 78 and the gas injector injects the process gas toward a primary plasma generation zone in the chamber; the first gas line is in fluid communication with an axially extending central bore in the injector body, and the second gas line is in fluid communication with an annular gas passage surrounding the central bore (see page 9-lines 28-29); the injector body is cylindrical shaped and the off-axis outlets are circumferentially spaced apart; the gas injector can inject the process gas at subsonic, sonic or supersonic velocity; the off-axis gas outlets inject process gas at an acute angle relative to the plane parallel to the exposed surface of the substrate; .

Claims 8, 10 and 40 are rejected under 35 U.S.C. 103(a) as being unpatentable over Chang, WO 99/57747 in view of Arami et al., U.S. Patent 5,958,140, or Goodyear et al., U.S. Patent 5,532,190, or Ballance et al., U.S. Patent 6,090,210, as applied to claims 1-7, 9, 11-14 and 39 above, and further in view of Ni et al., WO 00/41212.

Chang, Arami et al., Goodyear et al. and Ballance et al. are applied as above but do not expressly disclose that the gas injector is removably mounted in the dielectric window. Ni et al. discloses an apparatus comprising a gas injector removably mounted

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to a dielectric window, the reference also discloses that the most preferred mounting arrangement for the gas injector is a removable mounting arrangement (see page 13-line 20 to page 14-line 2). Therefore, in view of this disclosure, it would have been obvious to one having ordinary skill in the art at the time the invention was made to modify the apparatus of Chang modified by Arami et al., Goodyear et al. or Ballance et al., as to removably mount the gas injector to the dielectric member because such mounting arrangement is suitable and preferred, and also, cleaning of the gas injector can be facilitated.

Claims 15 are rejected under 35 U.S.C. 103(a) as being unpatentable over Chang, WO 99/57747 in view of Arami et al., U.S. Patent 5,958,140, or Goodyear et al., U.S. Patent 5,532,190, or Ballance et al., U.S. Patent 6,090,210, as applied to claims 1-7, 9, 11-14 and 39 above, and further in view of Powell et al., U.S. Patent 6,287,643.

Chang, Arami et al., Goodyear et al. and Ballance et al. are applied as above but do not expressly disclose that the gas injector is further provided with an electrically conducting shield. Powell et al. discloses an apparatus comprising a gas injection tube 84 provided with an electrically conducting shield (see col. 9, lines 33-50) that minimizes plasma ignition until the gas reaches the main chamber (see Fig. 5 and col. 7-line 57 to col. 9-line 50). Therefore, in view of this disclosure, it would have been obvious to one having ordinary skill in the art at the time the invention was made to modify the apparatus of Chang modified by Arami et al., Goodyear et al. or Ballance et al., so as to further comprise an electrically conducting shield for the gas injector in order to

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minimize the plasma ignition within the injector because plasma ignition within the injector can result in detrimental effects such as damage to the injector as well as uniformity problems with processing within the chamber.

Response to Arguments

Applicant's arguments with respect to claims 1-15 and 39-42 have been considered but are most in view of the new ground(s) of rejection.

Conclusion

Any inquiry concerning this communication or earlier communications from the examiner should be directed to Luz L. Alejandro whose telephone number is 571-272-1430. The examiner can normally be reached on Monday to Thursday from 7:30 to 6:00.

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Gregory L. Mills can be reached on 571-272-1439. The fax phone number for the organization where this application or proceeding is assigned is 703-872-9306.

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Information regarding the status of an application may be obtained from the Patent Application Information Retrieval (PAIR) system. Status information for published applications may be obtained from either Private PAIR or Public PAIR. Status information for unpublished applications is available through Private PAIR only. For more information about the PAIR system, see http://pair-direct.uspto.gov. Should you have questions on access to the Private PAIR system, contact the Electronic Business Center (EBC) at 866-217-9197 (toll-free).

Luz L. Alejandro Primary Examiner Art Unit 1763

March 5, 2004